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Discrete Power & Signal Technologies

TN6725A



NPN Darlington Transistor

This device is designed for applications requiring extremely high current gain at collector currents to 1A. Sourced from Process 05. See MPSA14 for characteristics.

Absolute Maximum Ratings*

T_{A = 25°C} unless otherwise noted

| Symbol | Parameter | Value | Units |
|----------------------|--------------------------------------------------|-------------|-------|
| V _{CES} | Collector-Emitter Voltage | 50 | V |
| V _{CBO} | Collector-Base Voltage | 60 | V |
| V _{EBO} | Emitter-Base Voltage | 12 | V |
| Ic | Collector Current - Continuous | 1.2 | Α |
| T _{J, Tstg} | Operating and Storage Junction Temperature Range | -55 to +150 | °C |

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150°C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics TA=

T_{A = 25°C unless otherwise noted}

| Symbol | Characteristic | Max | Units |
|-------------------|--------------------------------------------|---------|------------|
| | | TN6725A | |
| P _D | Total Device Dissipation Derate above 25°C | 1 8 | W mW/°C |
| R _θ JC | Thermal Resistance, Junction to Case | 50 | °C/W |
| R _{θJA} | Thermal Resistance, Junction to Ambient | 125 | °C/W |

NPN Darlington Transistor (continued)

Electrical Characteristics

T_{A = 25°C} unless otherwise noted

| Symbol | Parameter | Test Conditions | Min | Max | Units |
|----------------------|--------------------------------------|------------------------------------------------------------------------------------------------------|--------------------------|------------|-------|
| OFF CHA | RACTERISTICS | | | | |
| BV _{CES} | Collector-Emitter Breakdown Voltage | I _C = 1 mA | 50 | | V |
| BV _{CBO} | Collector-Base Breakdown Voltage | I _C = 100 μA | 60 | | V |
| BV _{EBO} | Emitter-Base Breakdown Voltage | I _E = 10 μA | 12 | | V |
| I _{CBO} | Collector Cutoff Current | V _{CB} = 40 V | | 100 | nA |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = 10 V | | 100 | nA |
| ON CHAI | RACTERISTICS* | | | | |
| h _{FE} | DC Current Gain | I_{C} = 200 mA, V_{CE} = 5 V I_{C} = 500 mA, V_{CE} = 5 V I_{C} = 1A, V_{CE} = 5 V | 25,000 15,000 4000 | 40,000 | - |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = 200 mA, I _B = 2 mA I _C = 1 A, I _B = 2 mA | | 1.0 1.5 | V |
| V _{BE(sat)} | Base-Emitter Saturation Voltage | I _C = 1 A, I _B = 2 mA | | 2 | V |
| V _{BE(on)} | Base-Emitter On Voltage | I _C = 1 A, V _{CE} = 5.0 V | | 2 | V |
| SMALL S | IGNAL CHARACTERISTICS | | | | |
| C _{cb} | Output Capacitance | V _{CB} = 10 V, I _E = 0, f = 1MHz | | 10 | pF |
| h _{fe} | Small Signal Current Gain | I _C = 200 mA,V _{CE} = 5 V, f=100MHz | 1 | 10 | - |

^{*}Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 1.0%

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|--------------------------|---------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
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